Special Topics on Basic EECS I Design Technology Co-Optimization
Lecture 13

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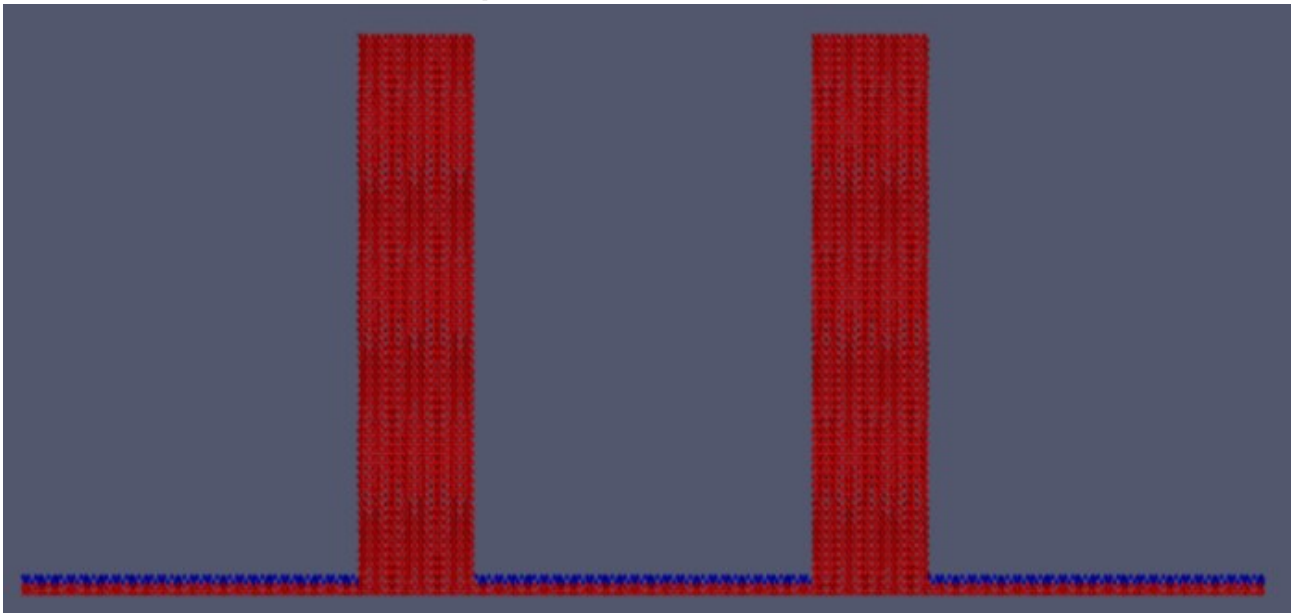Department of Electrical Engineering and Computer Science
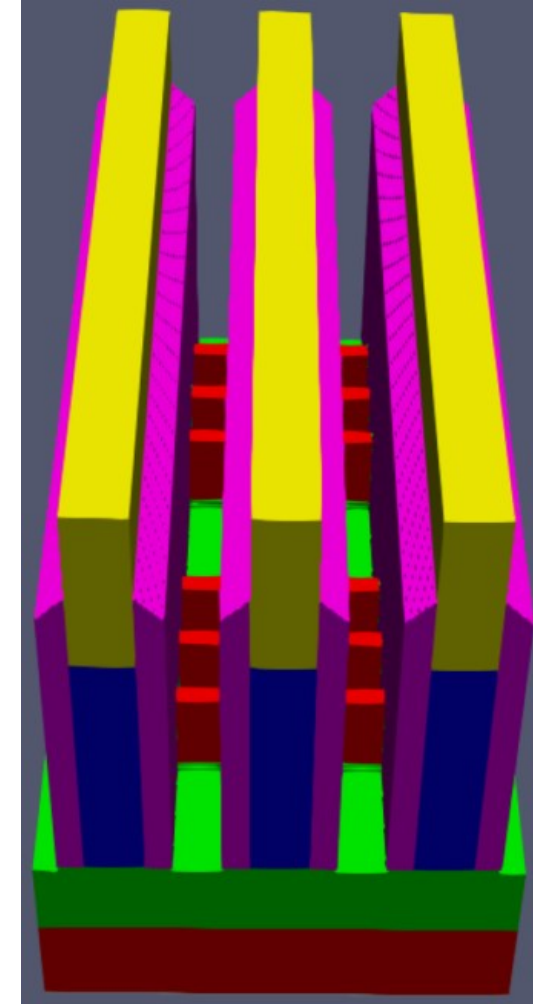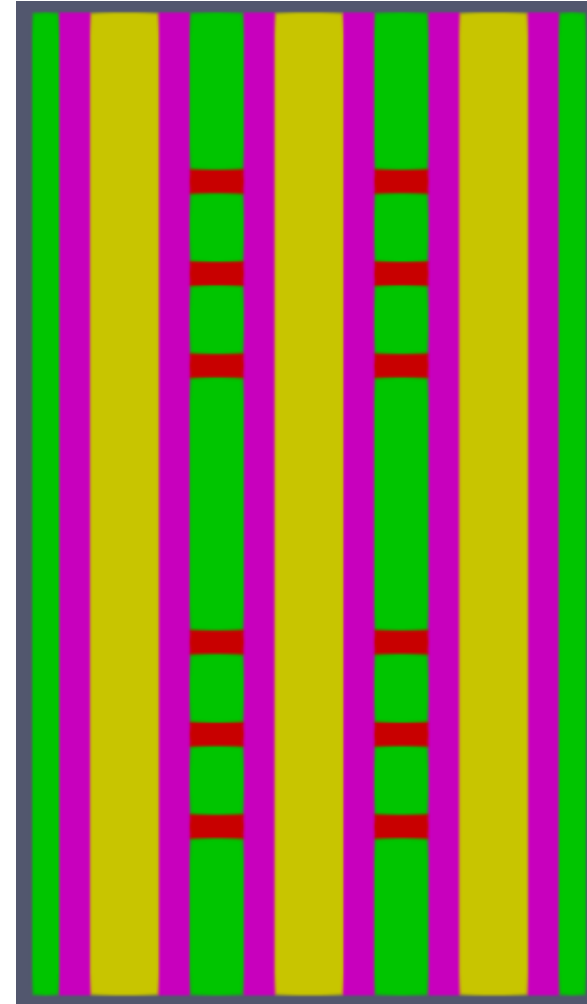Gwangju Institute of Science and Technology (GIST)

L13

Coming back to the FinFET

- There are fins.
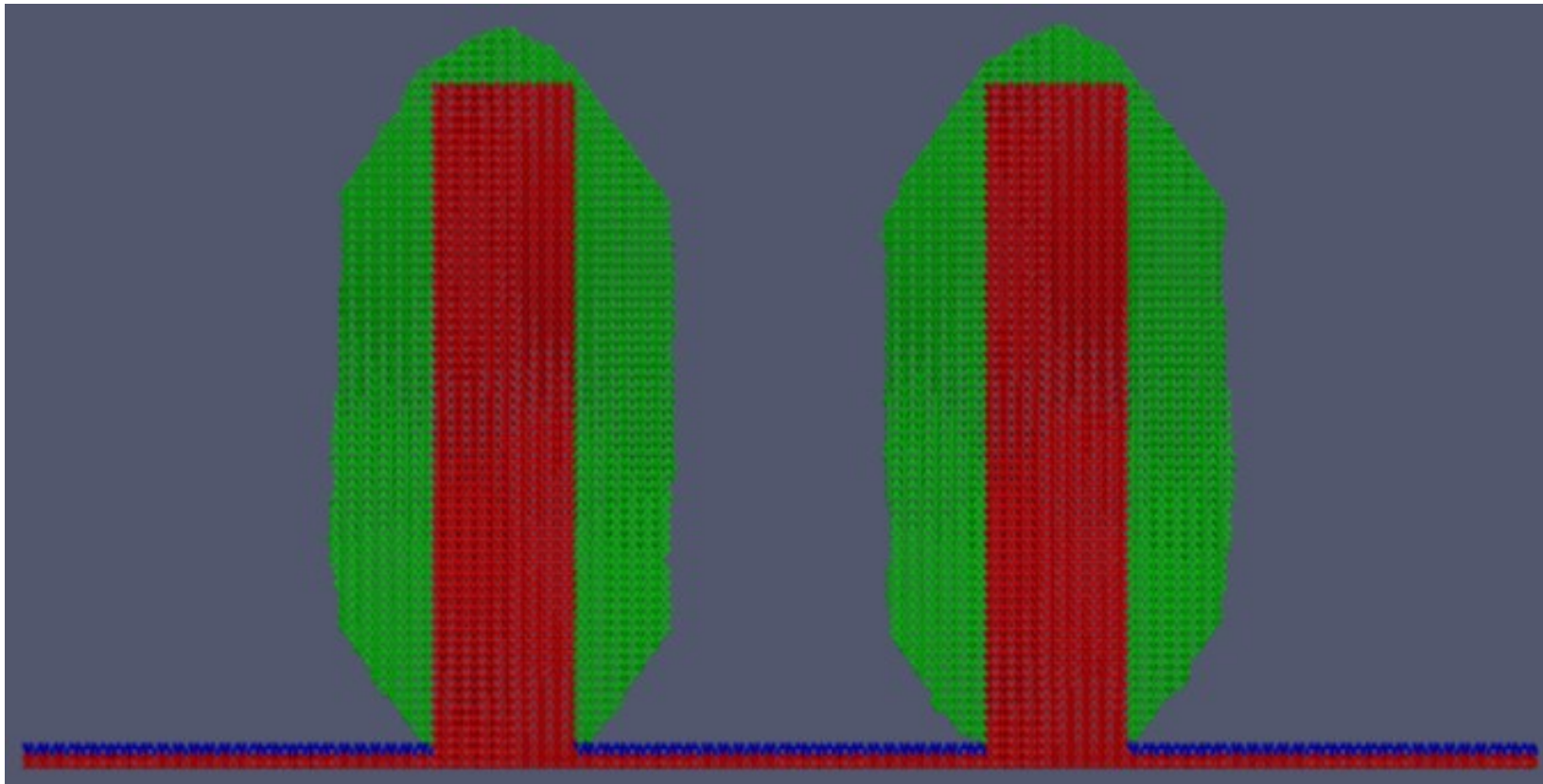 - Separated by 20 nm
  - Test a two-fin structure. (32-nm-tall)

20 nm

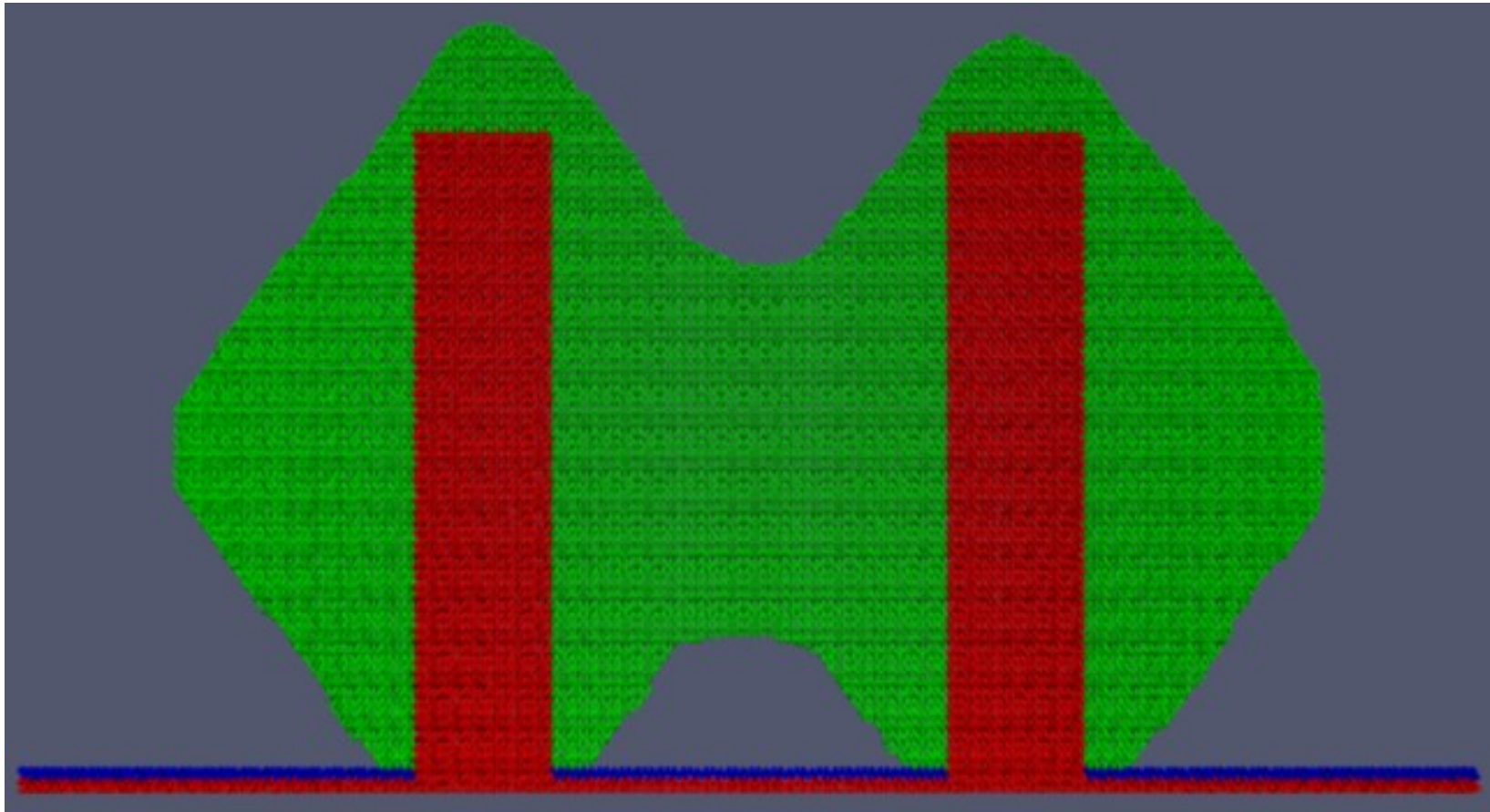# Thickness ~ 4.5 nm

- They are separated.
  - {111} surfaces are observed.
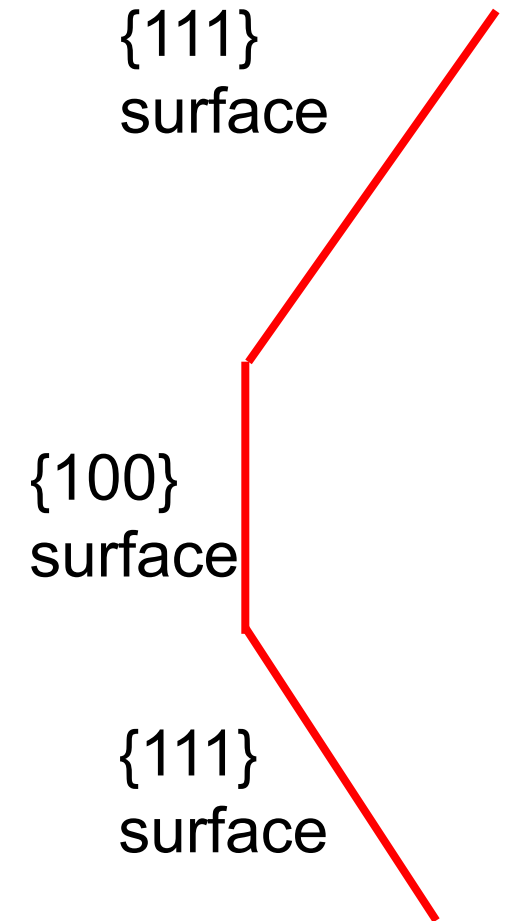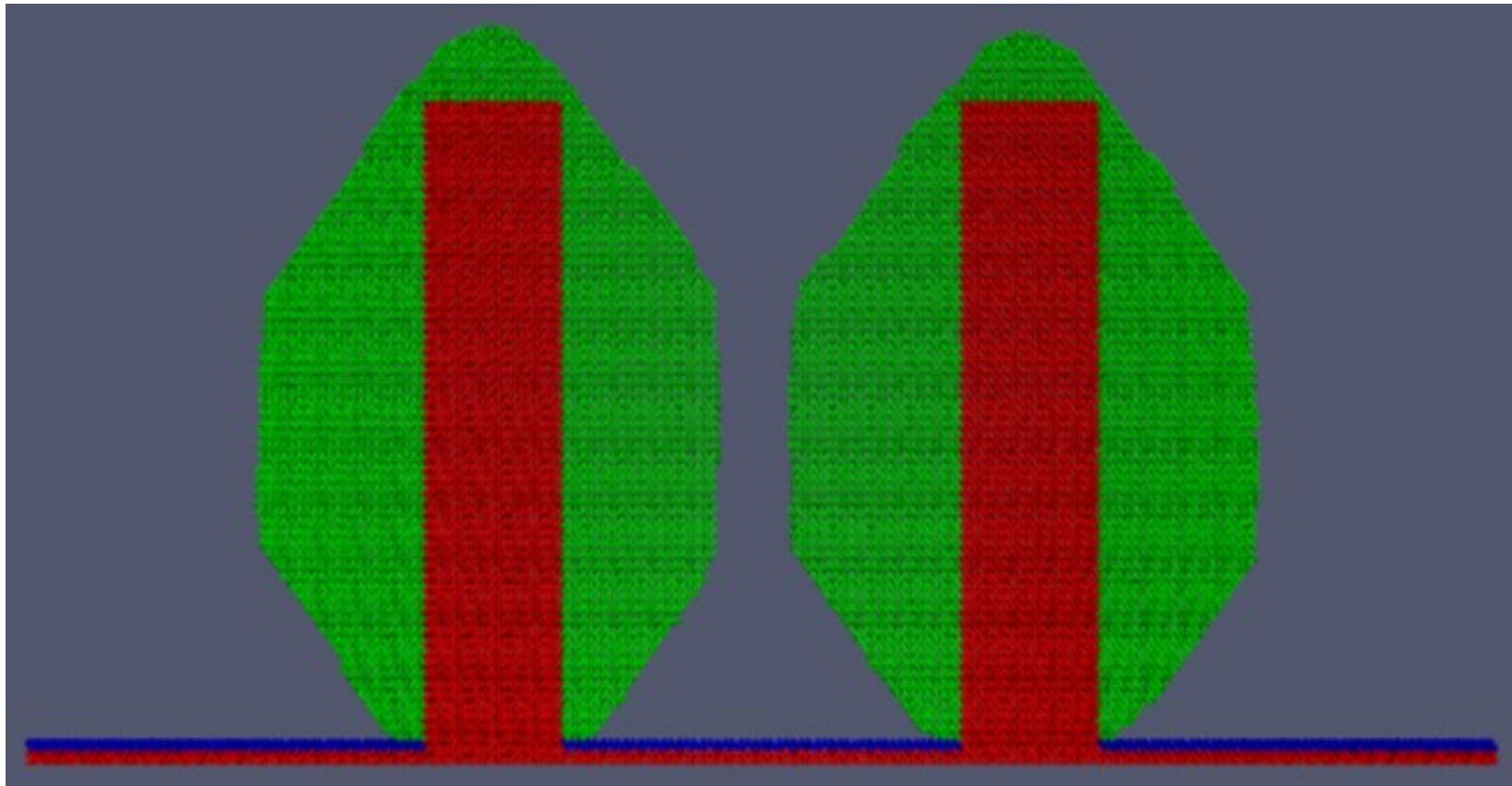 - On the top surface, {311} surfaces are dominant.

Double the number of atoms.

- They are bridged. It looks like mushrooms.
  - (Can we trust this result?)

In between,

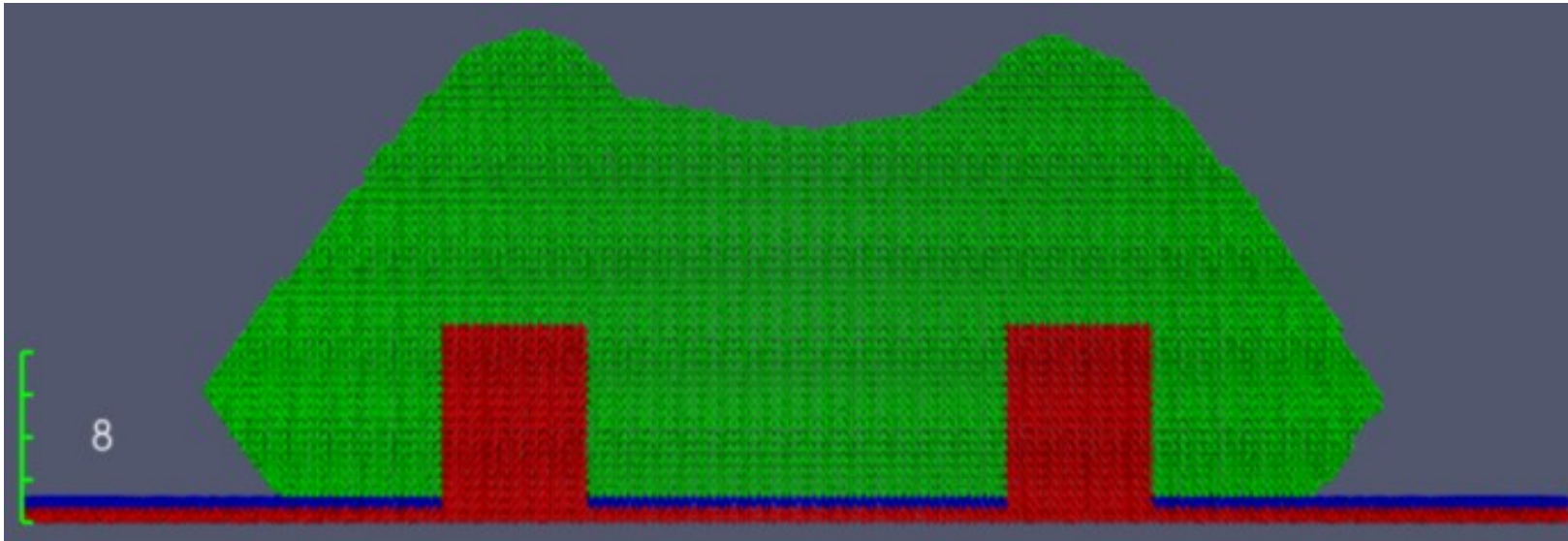- We can find a condition of unmerged fins.
  - The fin shape can be well approximated.

{111} surface

{100} surface

{111} surface
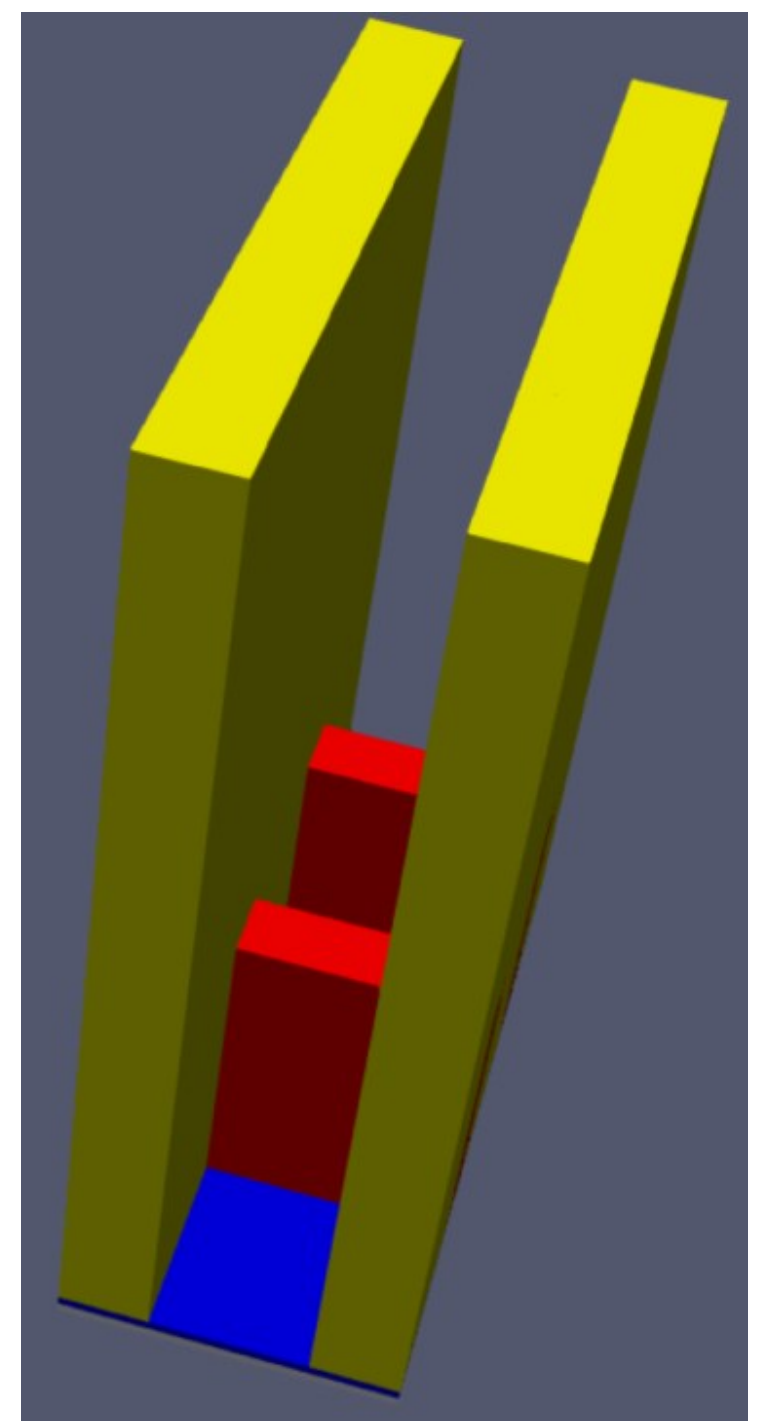
Impact of fin height

- Consider 8-nm-tall fins.
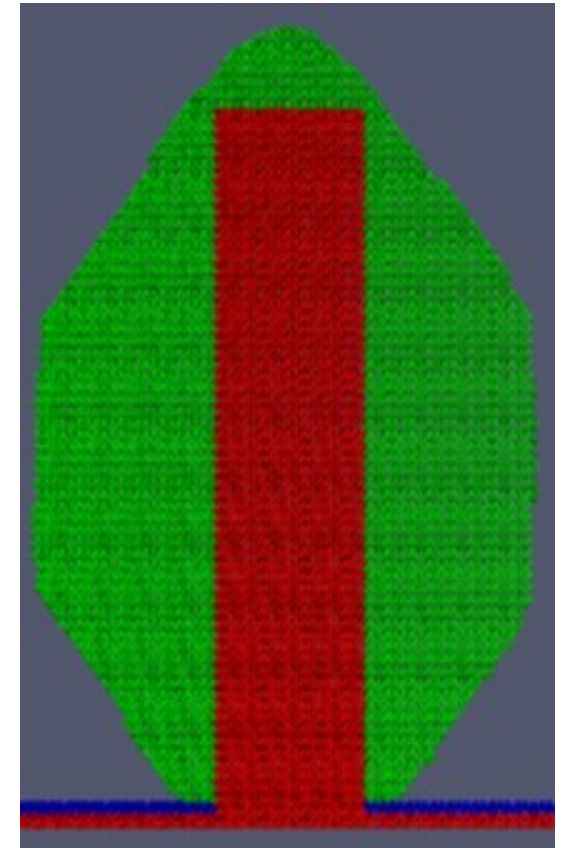 - Repeat the previous test. (The same number of atoms in the last slide)
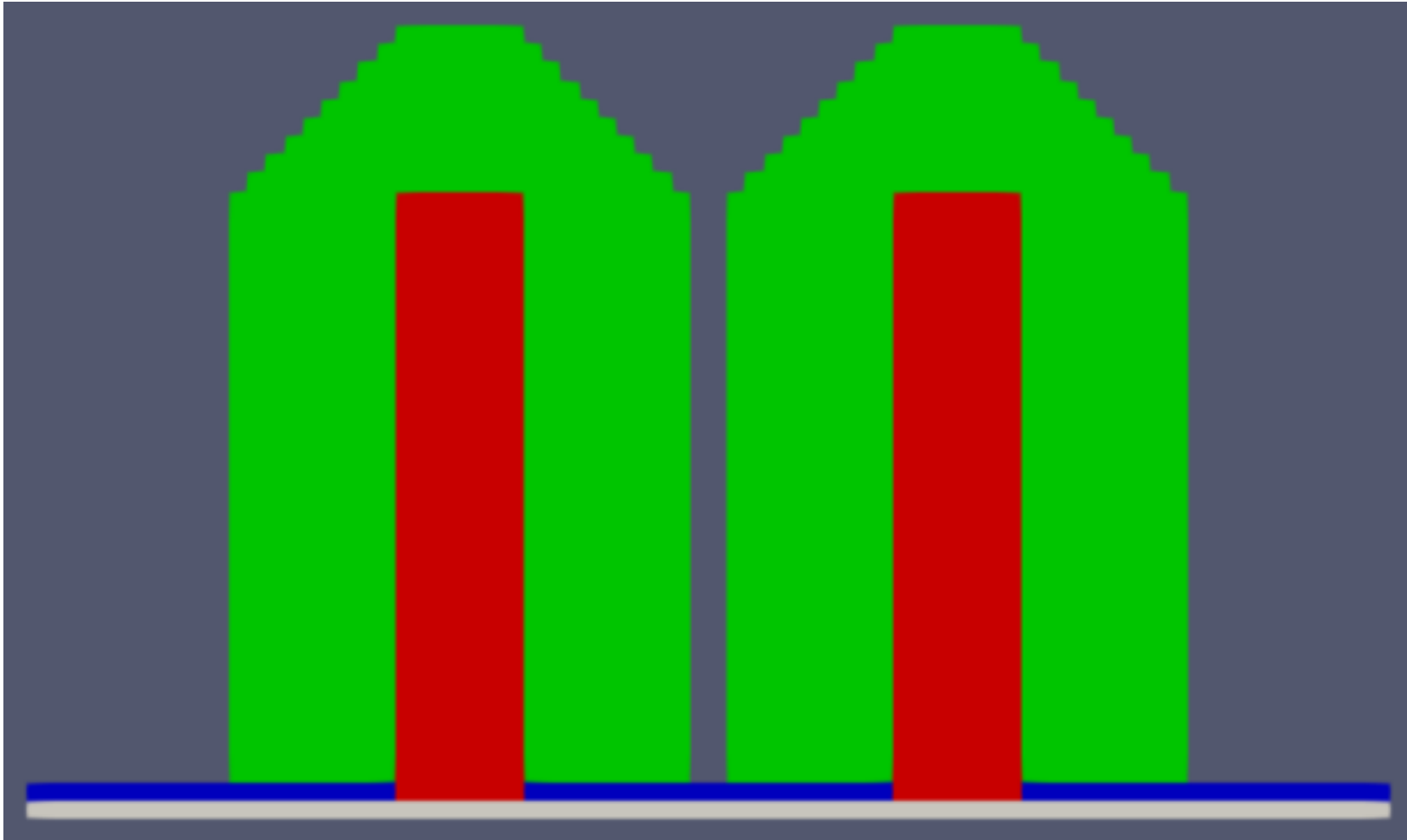
Try this.

- Construct a test structure.
  - 34 nm (= 9 +16 + 9) by 74 nm (= 20 + 7 + 20 + 7 + 20)
  - (The colors of the regions do not matter.)
  - Now, we are ready to test the selective epitaxial growth.

```
model (name="model_sd") {
    select (region="Fin")
    select (region="SD")
}
```

Isotropic depo with a thickness of 9 nm

- No boundary condition. 45 degree.

New `growth` statement

- This new statement takes three spec arguments.
  - Name of the added region: `region`
  - Name of the material selectivity: `model`
  - (Minimum) number of voxels to be added: `number`

```
growth (region="SD",model="model_sd",number=12000)
```

  - DO NOT increase `number` too aggressively.

- Main idea
  - Check the existing surfaces.
  - {111} surfaces are approximated as diagonal surfaces. (45°)

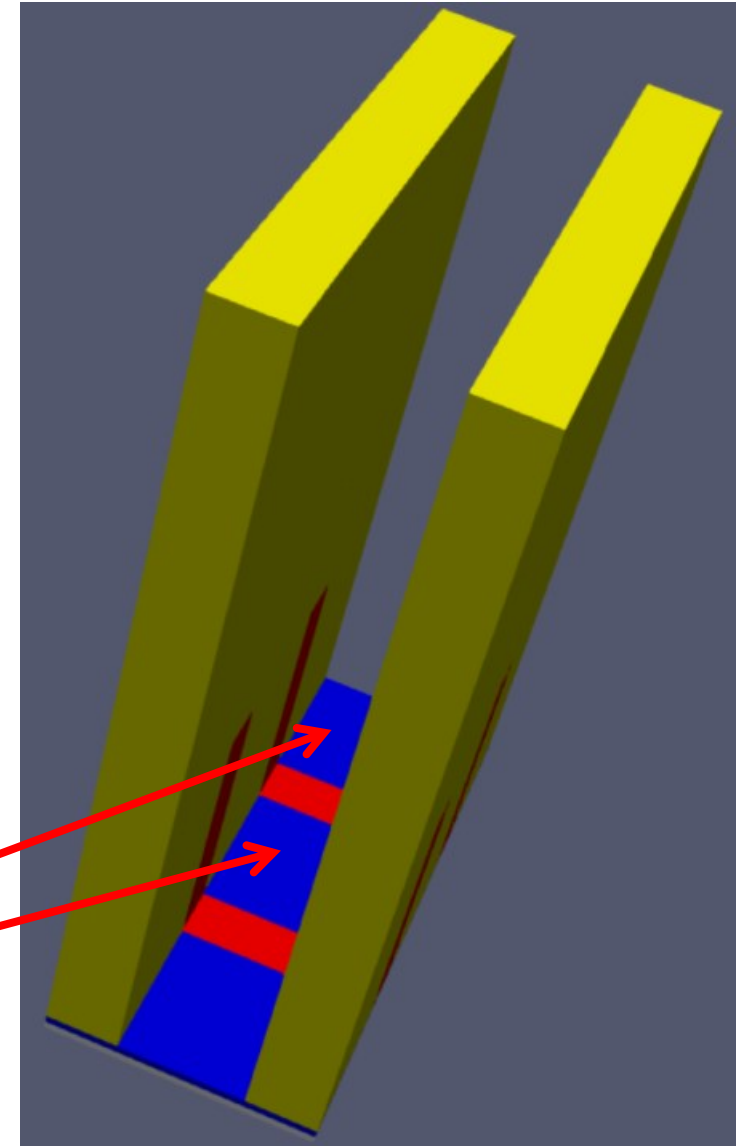# When the number of voxels is 12000,

- We have a similar profile.
  - Of course, details cannot be reproduced.
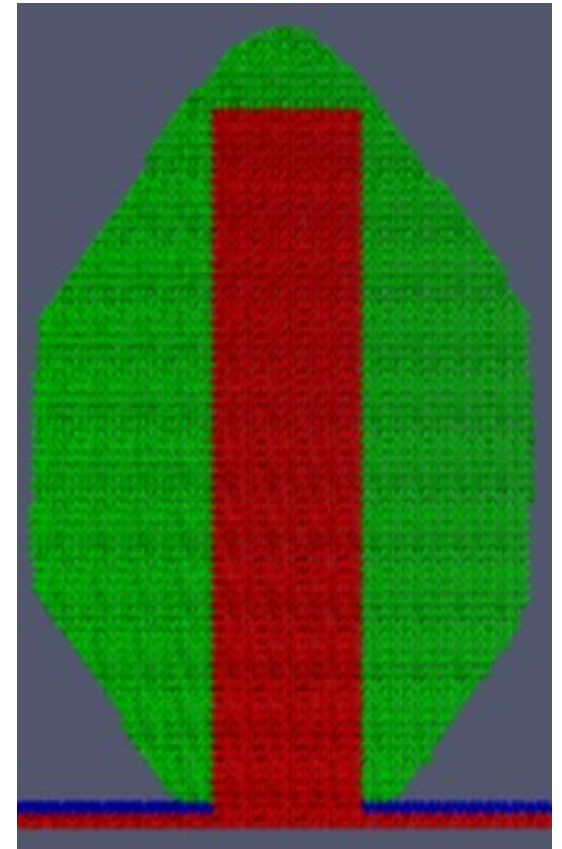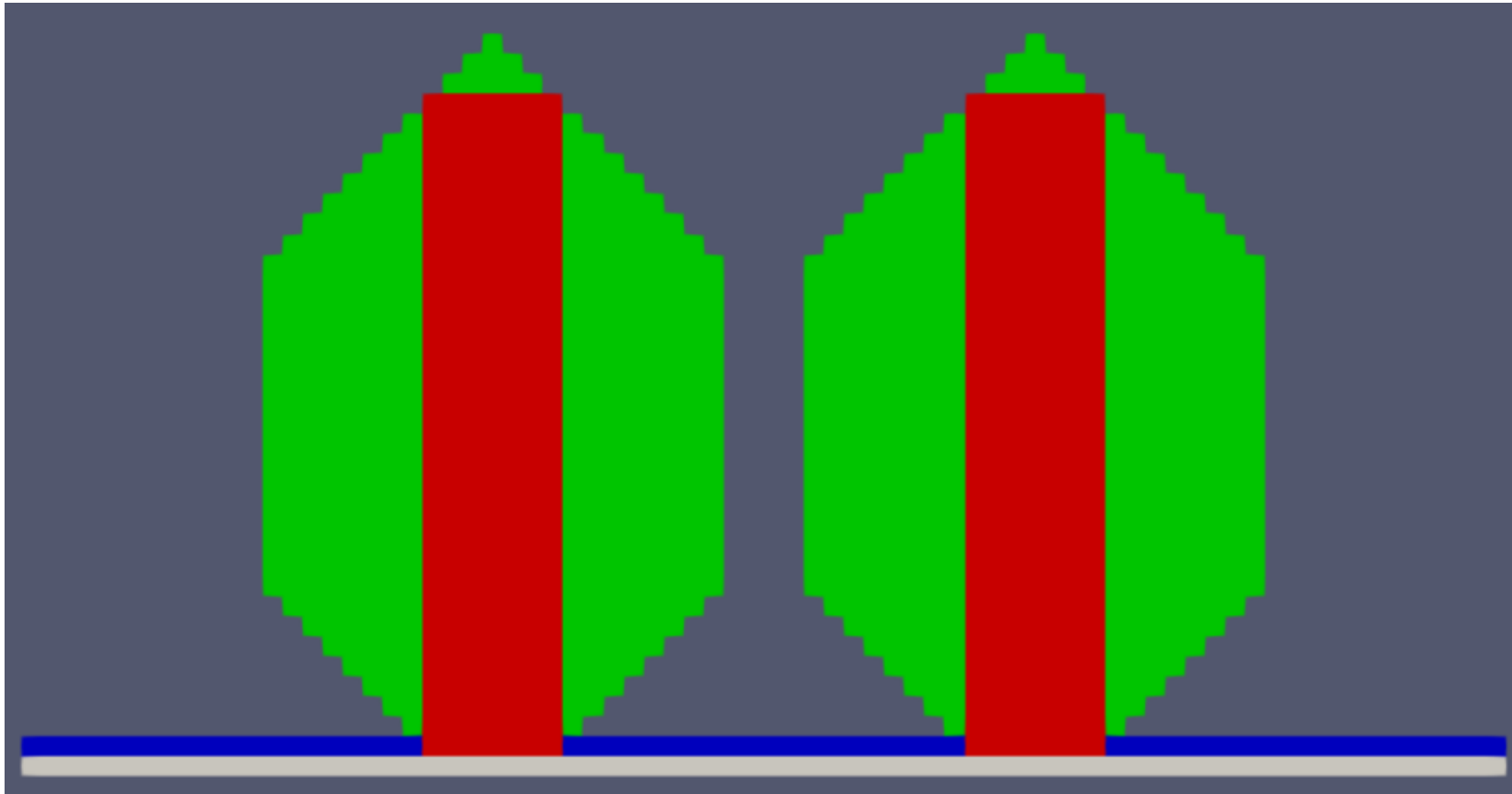
Three-dimensional shape

- Cavity etching
  - The 32-nm-tall fin is etched anisotropically.
  - The fin underneath the spacer is not etched. ➔ In reality, these parts are also etched.
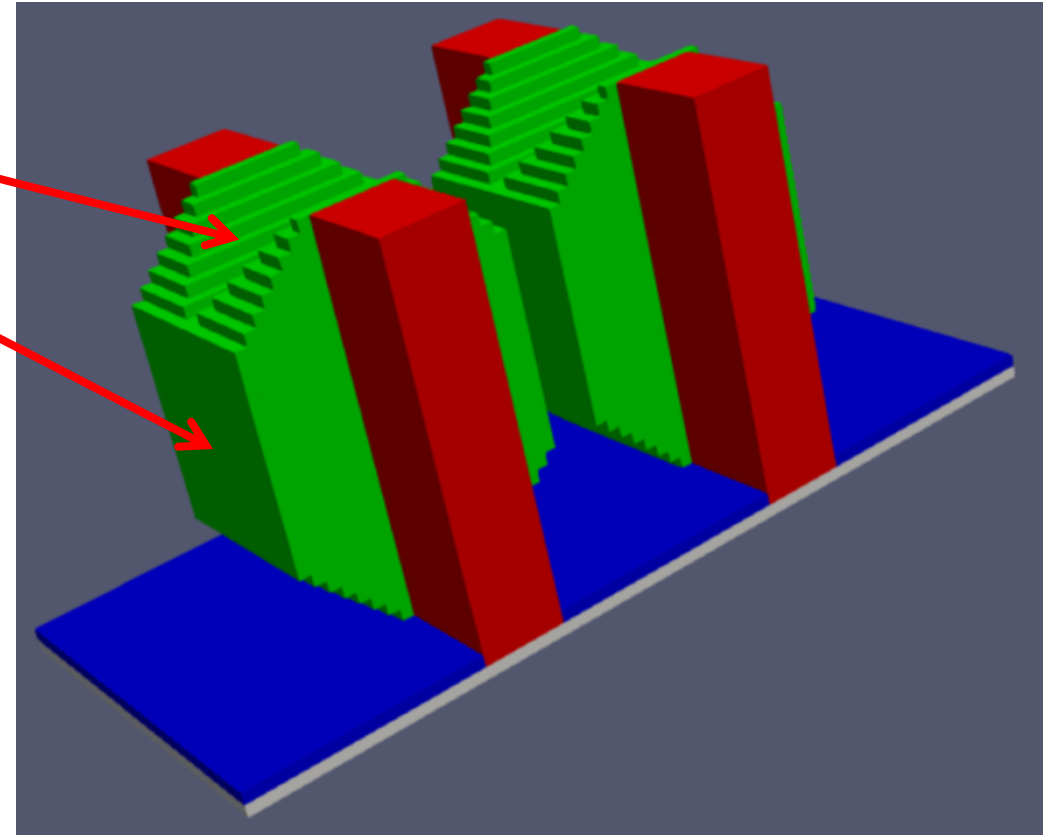 - Etch depth is equal to the fin height. ➔ In reality, it is not.

There is no fin.

Growth after cavity etching

- Contribution from two channels is dominant.
    - In this example, increased `number` introduces more voxels to make a diamond-like shape.

```
model (name="model_sd") {
    select (region="Fin")
    select (region="SD")
    neighbor (region="Spacer")
}
```

Homework#13

- Due: 08:00 on Nov. 3

- Submit a report through the GIST LMS system.
  - Construct the simple structure used in the L13 lecture material. Then, by using a `growth` statemtent, grow the epitaxial layer.

Thank you!